

# P0102DN

# Sensitive 0.8 A SCR thyristor

Datasheet - production data

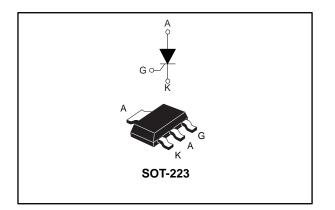
Unit

А

V

mΑ

°C



Symbol

I<sub>T(RMS)</sub>

Vdrm/Vrrm

lgт

T<sub>i</sub> max.

Description

0.8 A P0102DN SCR thyristor is suitable for all applications where available gate current is limited. This device offers a high blocking voltage of 400 V, ideal for applications like interrupters circuits in 110 V mains regions.

Thanks to highly sensitive triggering levels, the

The surface mount SOT-223 package allows compact, SMD based designs for automated manufacturing.

**Table 1: Device summary** 

Value

0.8

400

0.2

125

- I<sub>T(RMS)</sub> 0.8 A
- 125 °C max T<sub>i</sub>
- Low 0.2 mA gate current
- 400 V V<sub>DRM</sub>/V<sub>RRM</sub>
- ECOPACK<sup>®</sup>2 compliant component

### **Applications**

- Proximity sensors
- Gate driver for large Thyristors
- Overvoltage crowbar protection
- Ground fault circuit interrupters
- Arc fault circuit interrupter
- Solid state relay pilot circuit
- Standby mode power supplies
- Residual current detector

DocID031119 Rev 1

This is information on a product in full production.

1

### Characteristics

### Table 2: Absolute maximum ratings (limiting values), T<sub>j</sub> = 25 °C unless otherwise specified

Symbol	Parameter	Value	Unit		
I <sub>T(RMS)</sub>	RMS on-state current (180 ° conduction	Tamb = 70 °C	0.8	٨	
I <sub>T(AV)</sub>	Average on-state current (180 ° conduc	tion angle)	$T_{amb} = 70^{\circ}C$	0.5	A
	Non repetitive surge peak on-state curr	t <sub>p</sub> = 8.3 ms	8	٨	
ITSM	$(T_j initial = 25 °C$			7	A
l²t	I <sup>2</sup> t value for fusing	t <sub>p</sub> = 10 ms	0.24	A <sup>2</sup> s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	f = 60 Hz	T <sub>j</sub> = 125 °C	50	A/µs
Vdrm/Vrrm	Repetitive peak off-state voltage		T <sub>j</sub> = 125 °C	400	V
Igм	Peak gate current t <sub>p</sub> = 20 µs		T <sub>j</sub> = 125 °C	1	А
P <sub>G(AV)</sub>	Average gate power dissipation	T <sub>j</sub> = 125 °C	0.1	W	
T <sub>stg</sub>	Storage junction temperature range	-40 to +150	°C		
Tj	Operating junction temperature	-40 to +125	°C		

### Table 3: Electrical characteristics (T<sub>j</sub> = 25 °C unless otherwise specified)

Symbol	Test conditions		Value	Unit	
lgт	V- 12 V D = 140 O	Max.	200	μΑ	
Vgt	$V_{D} = 12 V, R_{L} = 140 \Omega$	Max.	0.8	V	
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, R_{GK} = 1000 \Omega$ $T_j = 125 \text{ °C}$			0.1	V
V <sub>RG</sub>	I <sub>RG</sub> = 10 μA	Min.	8	V	
Ι <sub>Η</sub>	$I_T$ = 50 mA, $R_{GK}$ = 1000 $\Omega$	Max.	5	mA	
١L	I <sub>G</sub> = 1.2 x I <sub>GT</sub> , R <sub>GK</sub> = 1000 Ω	Max.	6	mA	
dV/dt	$V_D = 67 \ \% \ V_{DRM}, \ R_{GK} = 1000 \ \Omega $ $T_j = 125 \ ^\circ C$		Min.	75	V/µs

### Table 4: Static characteristics

Symbol	Test conditio	Value	Unit			
Vтм	I <sub>TM</sub> = 1.6 A, t <sub>p</sub> = 380 μs	T <sub>j</sub> = 25 °C	Max.	1.95	V	
Vto	Threshold voltage	T <sub>j</sub> = 125 °C	Max.	0.95	v	
R <sub>D</sub>	Dynamic resistance	T <sub>j</sub> = 125 °C	Max.	600	mΩ	
Idrm/Irrm	$V_D = V_{DRM}$ ; $V_R = V_{RRM}$ , $R_{GK} = 1000 \ \Omega$	T <sub>j</sub> = 25 °C	Maria	1	μA	
		T <sub>j</sub> = 125 °C	Max.	100		

### Table 5: Thermal parameters

Symbol	Parameter	Value	Unit	
Rth(j-t)	Junction to tab (DC)	30		
Rth(j-a)	Junction to ambient (DC)	$S^{(1)} = 5 \text{ cm}^2$	60	°C/W

### Notes:

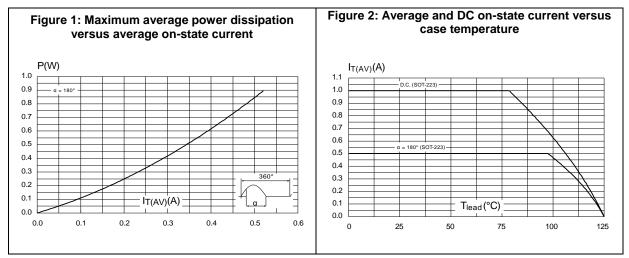
 $^{(1)}S$  = copper surface under tab.

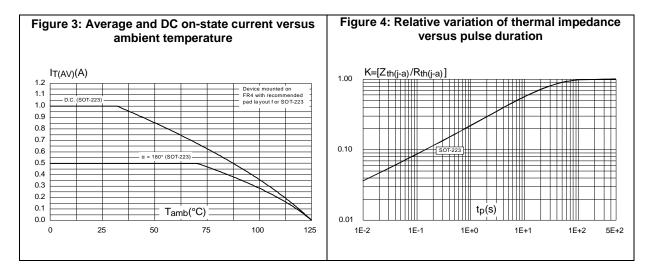


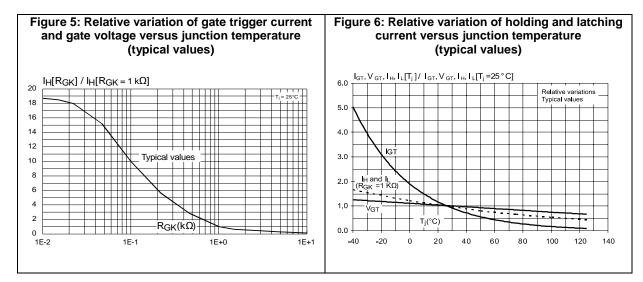
#### P0102DN

51

### 1.1 Characteristics (curves)



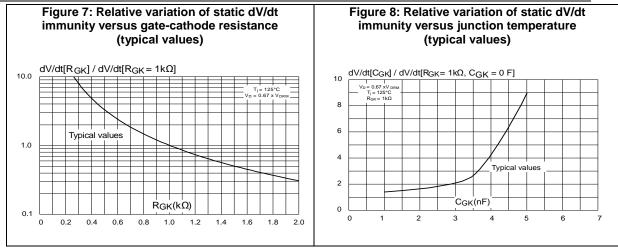


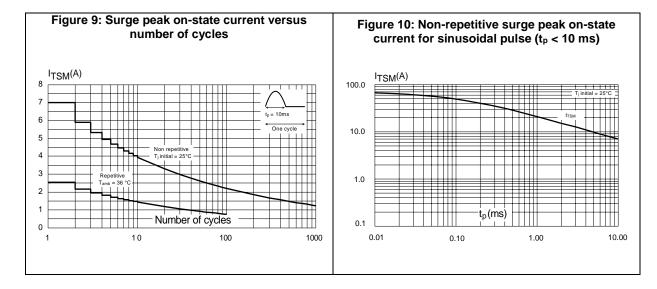


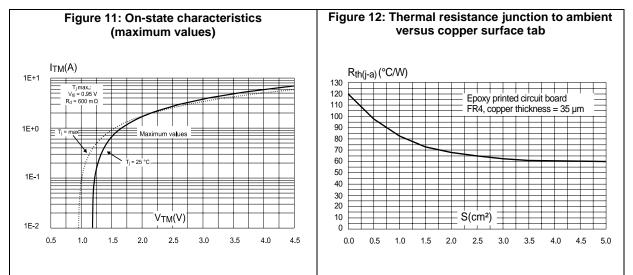
DocID031119 Rev 1

### Characteristics

#### P0102DN







DocID031119 Rev 1



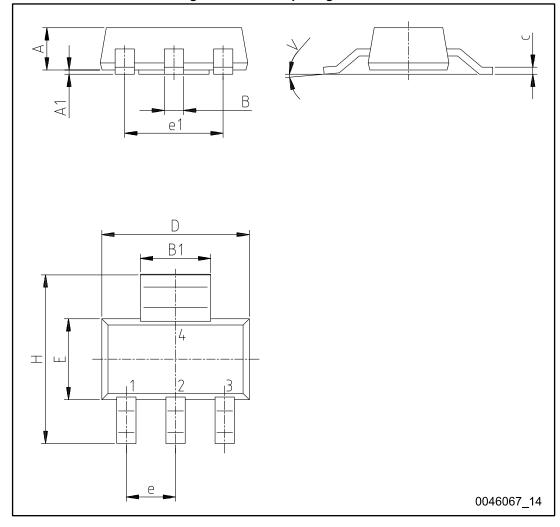
### 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

- Lead-free package
- Halogen free molding resin
- Epoxy meets UL94, V0

### 2.1 SOT-223 package information

### Figure 13: SOT-223 package outline





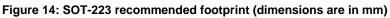
### Package information

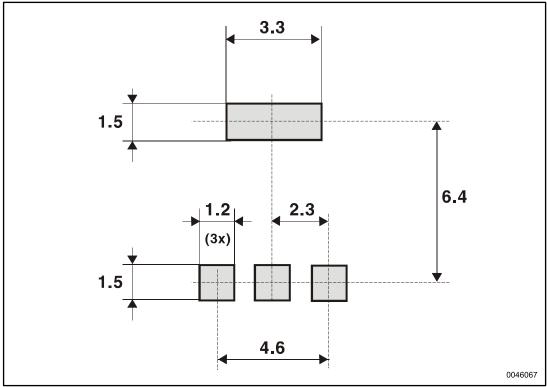
	Table 6: SOT-223 package mechanical data							
Dim		Millimeters			Inches <sup>(1)</sup>			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.8			0.0709		
A1	0.02		0.1	0.0008		0.0039		
В	0.6	0.7	0.85	0.0236	0.0276	0.0335		
B1	2.9	3	3.15	0.1142	0.1181	0.1240		
с	0.24	0.26	0.35	0.0094	0.0102	0.0138		
D <sup>(2)</sup>	6.3	6.5	6.7	0.2480	0.2559	0.2638		
е		2.3			0.0906			
e1		4.6			0.1811			
E	3.3	3.5	3.7	0.1299	0.1378	0.1457		
Н	6.7	7.0	7.3	0.2638	0.2756	0.2874		
V			10º			10°		

#### Notes:

<sup>(1)</sup>Inches dimensions given only for reference

<sup>(2)</sup>Does not include mold flash or protusions. Mold flash or protusions must not exceed 0.15 mm (0.006 inches)







## **3** Ordering information

Series P = sensitive SCR, high immunity	P01 02	D   	N   	- xx	xx	
Gate sensitivity						
02 = 200 μA						
Voltage D = 400 V						
Package						
N = SOT-223						
Delivery mode (Packing)						
5AA4 = Tape and reel 7"						

### Figure 15: Ordering information scheme

#### **Table 7: Ordering information**

Order code	Marking	ing Package Weight		Base qty.	Delivery mode	
P0102DN 5AA4	P2D	SOT-223	0.12 g	1000	Tape and reel 7"	

### 4 Revision history

### Table 8: Document revision history

Date	Revision	Changes
26-Oct-2017	1	Initial release.



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